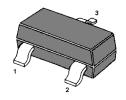


PNP Silicon Epitaxial Planar Transistor

For switching and amplifier applications. Especially suitable for AF-driver stages and low power output stages.

As complementary type the NPN transistor



1.BASE 2.EMITTER 3.COECTOR SOT-23 Plastic Package

Absolute Maximum Ratings ($T_a = 25$ °C)

Parameter	Symbol	Value	Unit
Collector Base Voltage	-V _{CBO}	40	V
Collector Emitter Voltage	-V _{CEO}	25	V
Emitter Base Voltage	-V _{EBO}	6	V
Collector Current	-I _C	1	Α
Power Dissipation	P _{tot}	350	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	Ts	- 55 to + 150	°C

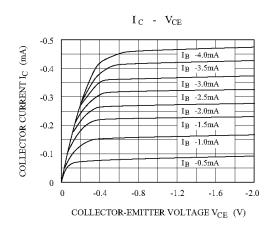
Characteristics at T_a = 25 °C

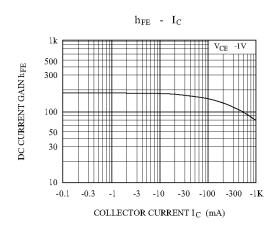
Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at -V _{CE} = 1 V, -I _C = 100 mA				-
at - V_{CE} = 1 V, - I_{C} = 800 mA	h _{FE}	200	400 -	
Collector Base Cutoff Current at -V _{CB} = 35 V	-I _{CBO}	-	100	nA
Emitter Base Cutoff Current at -V _{EB} = 6 V	-I _{EBO}	-	100	nA
Collector Base Breakdown Voltage at -I _C = 100 µA	-V _{(BR)CBO}	40	-	V
Collector Emitter Breakdown Voltage at -I _C = 2 mA	-V _{(BR)CEO}	25	-	٧
Emitter Base Breakdown Voltage at $-I_E = 100 \mu A$	-V _{(BR)EBO}	6	-	٧
Collector Emitter Saturation Voltage at -I _C = 800 mA, -I _B = 80 mA	-V _{CE(sat)}	-	0.5	٧
Base Emitter Saturation Voltage at $-I_C = 800 \text{ mA}$, $-I_B = 80 \text{ mA}$	-V _{BE(sat)}	-	1.2	٧
Base Emitter Voltage at $-V_{CE} = 1 \text{ V}$, $-I_{C} = 10 \text{ mA}$	-V _{BE(on)}	-	1	٧
Gain Bandwidth Product at $-V_{CE} = 10 \text{ V}$, $-I_C = 50 \text{ mA}$	f⊤	120	-	MHz

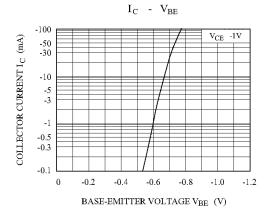
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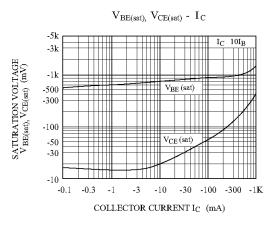


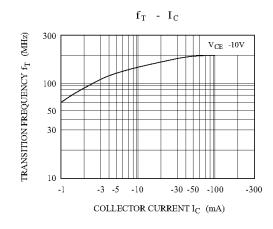


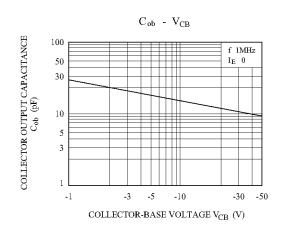
















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